1 P EAppl. No. 10/075,193

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Application Serial No. 10/075,193
Filing Date February 13, 2002
Inventor. Shenlin Chen et al.
Assignee Micron Technology, Inc.
Group Art Unit. 2813
Examiner Huynh, Y.
Attorney's Docket No. MI22-1927
Title: Methods of Forming a Capacitor Structure

RESPONSE TO DECEMBER 18, 2002 OFFICE ACTION

To:

Box Non-Fee Amendment

Assistant Commissioner for Patents

Washington, D.C. 20231

From:

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AMENDMENTS

Introductory Comments

The present Response is submitted in the Revised Amendment Format and therefore qualifies for waiver of provisions 37 CFR 1.121(a), (b), (c) and (d).